

R16

Code No: 132AA

JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY HYDERABAD

B.Tech I Year II Semester Examinations, April - 2018

ENGINEERING PHYSICS – II

(Common to EEE, ECE, CSE, EIE, IT, ETM)

Time: 3 hours

Max. Marks: 75

Note: This question paper contains two parts A and B.

Part A is compulsory which carries 25 marks. Answer all questions in Part A.

Part B consists of 5 Units. Answer any one full question from each unit. Each question carries 10 marks and may have a, b, c as sub questions.

PART- A

(25 Marks)

- 1.a) Show that matter waves velocity is greater than the velocity of light. [2]
- b) Explain Heisenberg uncertainty principle. [3]
- c) Write any three applications of direct band gap semiconductors. [2]
- d) Draw E-K diagram and explain briefly. [3]
- e) Define Polarization in dielectric materials. [2]
- f) Show that $P = \epsilon_0 E (\epsilon_r - 1)$. [3]
- g) Show that $\mu_r = 1 + \chi$. [2]
- h) What is superconductivity [3]
- i) What is nano scale? [2]
- j) Explain how nanomaterials show size dependent properties. [3]

PART-B

(50 Marks)

- 2.a) Derive an expression for energy of a particle in one dimensional potential box. [6+4]
 - b) Explain classification of materials based on band theory of solids. [6+4]
- OR
- 3.a) Explain how de-Broglie's hypothesis supports the concept of the duality. [4+6]
 - b) Describe Kronig-Penny model. [4+6]
- 4.a) Determine the concentration of holes in the valance band of intrinsic semiconductors. [5+5]
 - b) With neat diagram explain how Fermi energy level varies in n-type and p-type semiconductors with respect to temperature. [5+5]
- OR
- 5.a) With neat diagram explain energy diagram of PN junction diode. Explain how energy levels varies with respect to forward bias and reverse bias. [5+5]
 - b) Distinguish between n-type and p-type semiconductors. [5+5]
- 6.a) Derive an expression for ionic polarizability. [5+5]
 - b) Describe ferro electricity of dielectric materials. [5+5]
- OR
- 7.a) Explain BaTiO_3 structure and behaviour with respect to temperature. [5+5]
 - b) Derive an expression for Internal fields in dielectric material. [5+5]

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- 8.a) Explain origin of magnetic moment in magnetic materials.
b) What are the applications of superconductivity?

[5+5]

OR

- 9.a) Write a short note on properties of anti-ferro and ferri magnetic materials.
b) Distinguish between dia, para, ferro magnetic materials.

[5+5]

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- 10.a) Explain characterization of nanomaterials by using XRD.
b) Discuss CVD method for the preparation of nanomaterials.

[4+6]

OR

- 11.a) Explain PVD method for the preparation of nanomaterials.
b) With neat diagram explain Ball Mill method.

[5+5]

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